

1110-97825 PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appl. No.	: 10/586,445	)	Confirmation No.: 4877
Applicant	: NAKAMURA et al.	)	
Filed	: 17 July 2006	)	DO NOT ENTER: /RK/
Art Unit	: 1792	)	11/29/2010
Examiner	: KUNEMUND	)	
Docket No.	: 1110-97825	)	
Customer No.:	24628	)	
Title:	METHOD FOR PREDICTING PRECIPITATION BEHAVIOR OF OXYGEN IN SILICON SINGLE CRYSTAL, METHOD FOR DETERMINING PRODUCTION PARAMETER OF SILICON SINGLE CRYSTAL, AND STORAGE MEDIUM FOR STORING PROGRAM FOR PREDICTING PRECIPITATION BEHAVIOR OF OXYGEN IN SILICON SINGLE CRYSTAL	)	

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

**AMENDMENT**

Dear Sir:

The Office Action of 19 August 2010 has been carefully reviewed and the following amendments and remarks are made in response thereto:

**Amendments to the Claims** begin on page **2** of this paper.

**Remarks/Arguments** begin on page **8** of this paper.